

60V PNP LOW SATURATION MEDIUM POWER TRANSISTOR IN SOT89

Features

- BV_{CEO} > -60V
- I_C = -4.3A High Continuous Current
- $R_{SAT} = 32m\Omega$ for a Low Equivalent On-Resistance
- Low Saturation Voltage V_{CE(SAT)} < -65mV @ I_C = -1A
- h_{FE} Specified Up to -10A for High Current Gain Hold Up
- Complementary NPN Type: ZXTN2010Z
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Application

- Emergency Lighting Circuits
- Motor Driving (Including DC Fans)
- Backlight Inverters
- Power Switches
- Gate Driving MOSFETs and IGBTs

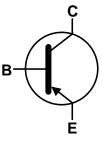
Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.05 grams (Approximate)

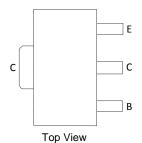
SOT89



Top View



Device Symbol



Pin Out

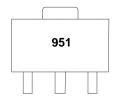
Ordering Information (Note 5)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
ZXTP2012ZTA	AEC-Q101	951	7	12	1,000
ZXTP2012Z-13R	AEC-Q101	951	13	12	4,000
ZXTP2012ZQTA	Automotive	951	7	12	1,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to https://www.diodes.com/quality/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



951 = Product Type Marking Code



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-100	V
Collector-Emitter Voltage	V _{CEO}	-60	V
Emitter-Base Voltage	V_{EBO}	-7	V
Base Current	I _B	-2	Α
Continuous Collector Current	Ic	-4.3	Α
Peak Pulse Current	I _{CM}	-15	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	D-	1.5	W
Linear Derating Factor	P _D	12	mW/°C
Power Dissipation (Note 7)	Б	2.1	W
Linear Derating Factor	P _D	16.8	mW/°C
Thermal Resistance, Junction to Ambient (Note 6)	R _{0JA}	83	°C/W
Thermal Resistance, Junction to Ambient (Note 7)	R _{0JA}	60	°C/W
Thermal Resistance, Junction to Leads (Note 8)	R _{eJL}	3.23	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes:

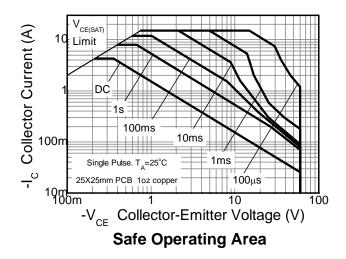
^{6.} For a device surface mounted on 25mm x 25mm x 1.6mm FR-4 PCB with high coverage of single sided 1oz copper, in still air conditions; device measured when operating in steady state condition.

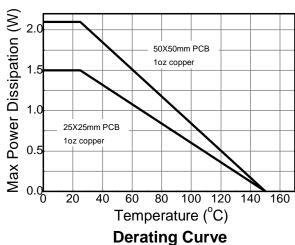
7. Same as note (6), except the device is mounted on 50mm x 50mm single sided 1oz weight copper.

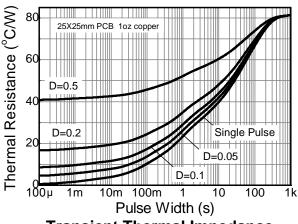
8. Thermal resistance from junction to solder-point (on the exposed collector pad).

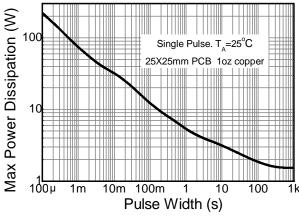


Thermal Characteristics and Derating Information









Transient Thermal Impedance

Pulse Power Dissipation



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

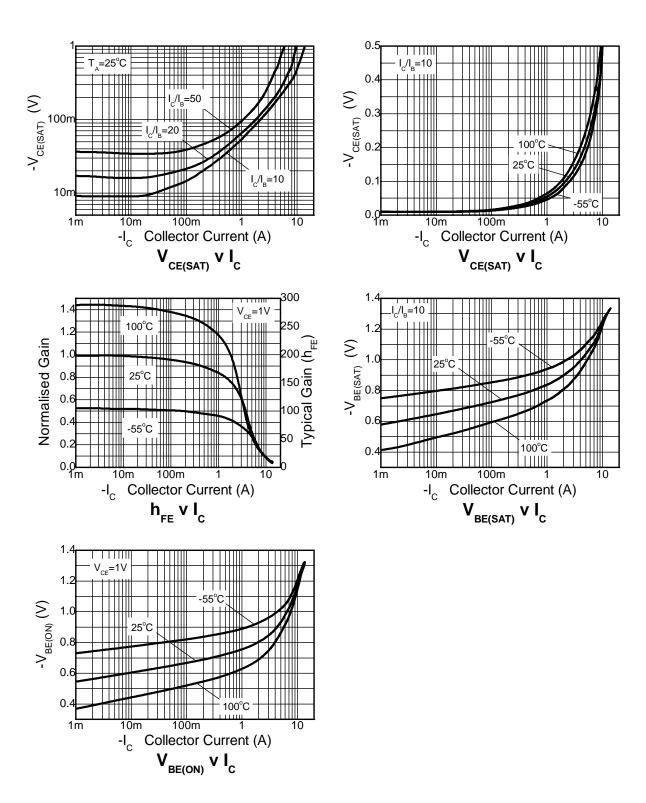
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-100	-120	_	V	$I_C = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CER}	-100	-120	_	V	$I_C = -1\mu A, R_B \le 1k\Omega$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-60	-80	_	V	$I_C = -10mA$
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8.1	_	V	I _E = -100μA
Collector Cutoff Current	I _{CBO}	_	< -1 —	-20 -500	nA nA	V _{CB} = -80V V _{CB} = -80V, T _A = +100°C
Collector Cutoff Current	l _{CER} R≤1kΩ	_	< -1 —	-20 -500	nA nA	V _{CB} = -80V V _{CB} = -80V, T _A = +100°C
Emitter Cutoff Current	I _{EBO}	_	< -1	-10	nA	V _{EB} = -6V
DC Current Transfer Static Ratio (Note 9)	h _{FE}	100 100 45 10	250 200 90 25	300 — —	_	$\begin{split} I_{C} &= -10 \text{mA}, \ V_{CE} = -1 \text{V} \\ I_{C} &= -2 \text{A}, \ V_{CE} = -1 \text{V} \\ I_{C} &= -5 \text{A}, \ V_{CE} = -1 \text{V} \\ I_{C} &= -10 \text{A}, \ V_{CE} = -1 \text{V} \end{split}$
Collector-Emitter Saturation Voltage (Note 9)	V _{CE(SAT)}	_	-14 -50 -75 -160	-20 -65 -110 -215	mV	I_C = -100mA, I_B = -10mA I_C = -1A, I_B = -100mA I_C = -2A, I_B = -200mA I_C = -5A, I_B = -500mA
Base-Emitter Saturation Voltage (Note 9)	$V_{BE(SAT)}$	_	-950	-1050	mV	$I_C = -5A$, $I_B = -500mA$
Base-Emitter Turn-on Voltage (Note 9)	$V_{BE(ON)}$	_	-840	-950	mV	$I_C = -5A$, $V_{CE} = -1V$
Transitional Frequency (Note 9)	f⊤	_	120	_	MHz	$I_C = -100 \text{mA}, V_{CE} = -10 \text{V},$ f = 50 MHz
Output Capacitance	C_{OBO}	_	48	_	pF	$V_{CB} = -10V$, $f = 1MHz$
Switching Time	t _{ON}	_	39 370	_	ns	$V_{CC} = -10V, I_C = -1A,$ $I_{B1} = -I_{B2} = -100mA$

Note: 9. Me

9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

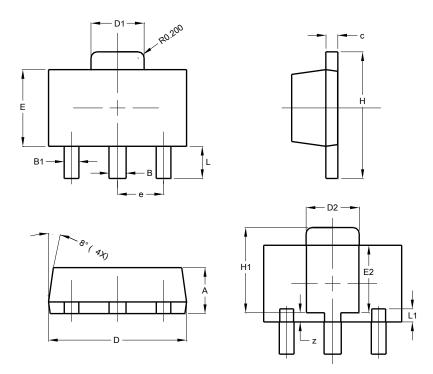




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89

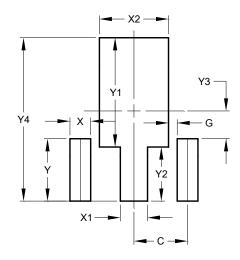


SOT89					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.50	0.62	0.56		
B1	0.42	0.54	0.48		
С	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.62	1.83	1.733		
D2	1.61	1.81	1.71		
E	2.40	2.60	2.50		
E2	2.05	2.35	2.20		
е	-	-	1.50		
Н	3.95	4.25	4.10		
H1	2.63	2.93	2.78		
L	0.90	1.20	1.05		
L1	0.327	0.527	0.427		
Z	0.20	0.40	0.30		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89



Dimensions	Value (in mm)
С	1.500
G	0.244
X	0.580
X1	0.760
X2	1.933
Υ	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530



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